### Russian Academy of Sciences

# Russian Foundation for Basic Research Yaroslavl Branch of the Institute of Physics and Technology Yaroslavl Demidov State University

Scientific Educational Center "Nanotechnology and Innovations" Center for Collective Use "Diagnostics of Micro- and Nanostructures"

#### II INTERNATIONAL CONFERENCE

on

# MODERN PROBLEMS IN PHYSICS OF SURFACES AND NANOSTRUCTURES (ICMPSN-2012)

#### SCIENTIFIC PROGRAM

Tuesday, May 22th, 2012

Arrival of the participants. Hotel accommodation

Summer school for young researchers

Wednesday, May 23<sup>th</sup>, 2012

Conference Hall in Park-Hotel Yaroslavl

9.00-10.00 Registration of participants

10.00-10.10 Opening the conference. Welcome word of the Head of Organizing Committee A.S. Rudy

#### Session 1. Physics and Technology of Nanostructures

Session Chairman: V.F. Lukichev

10.10-10.35 I1-1 Epitaxial graphene on Ir(111) – a playground for the

(invited) fabrication of graphene hybrid materials

T. Michely

II. Physikalisches Institut, Universität zu Köln, German

10.40-11.05 I1-2 Diffusion and growth of para-sexiphenyl molecular

(invited) films

G. Hlawacek

MESA+ Research Institute, University of Twente,

Enschede, The Netherlands

#### 11.10-11.20 Coffee break

11.20-11.45	I1-3 (invited)	Novel low-dimensional phases of carbon and inorganic materials: insights from DFT simulations and TEM experiments <u>A. Krasheninnikov</u> University of Helsinki, Helsinki, Finland
11.50-12.15	I1-4	Plasmons enhance near-field radiative heat transfer
	(invited)	for graphene-covered dielectrics
	, ,	V. B. Svetovoy
		MESA+ Institute for Nanotechnology, University of
		Twente, Enschede, The Netherlands
12.20-12.45	I1-5	Defects and electronic structure of CIS thin films:
	(invited)	revision
	` ,	M.G. Ganchenkova
		MEPHI, Moscow, Russia
12.50-13.15	<b>I1-6</b>	Next Generation Lithography – mythes and reality
	(invited)	S. I. Zaitsev
		IMT RAS, Chernogolovka, Russia

#### 13.20-14.30 Lunch

Session 2. Physics of thin film growth			
Session Chairi	man: K.V. l	Rudenko	
14.30-14.55	I1-7	Quantum Mechanical nanoscale magic: the growth of	
	(invited)	single 7-layer height Pb islands	
		M. C. Tringides	
		Ames Laboratory –USDOE, USA	
15.00-15.25	<b>I1-8</b>	<b>Advances in the Self Learning Kinetic Monte Carlo</b>	
	(invited)	Method and their application to cluster diffusion and	
		morphological evolution on metal surfaces	
		T.S. Rahman	
		University of Central Florida, Orlando, USA	
15.30-15.45	01-1	Influence of doping on the properties of Ge-Sb-Te	
		thin films for phase – change memory devices	
		A. Sherchenkov	
		MIET, Moscow, Russia	
15.50-16.05	<b>O1-2</b>	Metal nanolayer formation on crystal faces	
		with unlike electric charge	
		V. Haiduchok	
		Institute of materials, SCR "Carat" Lviv, Ukraine	

## 16.10-16.25 O1-3 Deposition of HfO<sub>2</sub> gate dielectric in ALD processes and its properties

A. Miakonkikh

Institute of Physics and Technology, Russian Academy of Sciences, Moscow, Russia

#### 16.30-19.00 Yaroslavl downtown sightseeing tour

### Thursday, May 24<sup>th</sup>, 2012

#### Conference Hall in Park-Hotel Yaroslavl

#### Session 3. Modeling of Surface Phenomena

Session Chair	man: O.S. 7	Γrushin
9.00-9.25	<b>I2-1</b>	Electrostatic interactions in nanoscale systems
	(invited)	Sahin Buyukdagli
		Aalto University, Espoo, Finland
9.30-9.55	<b>I2-2</b>	Unifying model of driven polymer translocation
	(invited)	T. Ala-Nissila
		Aalto University, Espoo, Finland
10.00-10.25	<b>I2-3</b>	Self-organization of nanostructures in ultra-thin films
	(invited)	K.R. Elder
		Oakland University, Rochester MI, USA
10.30-10.45	<b>O2-1</b>	Detailed structure and transformations of grain
		boundaries in graphene
		Ossi Lehtinen
		University of Helsinki, Helsinki, Finland
10.50-11.05	<b>O2-2</b>	Controlling of the size and density of three-
		dimensional islands self-assembled in kinetic Monte
		Carlo simulations
		F. F. Leal
		Instituto de Educação, Ciência e tecnologia Fluminense,
		Rio de Janeiro, Brazil
11.10-11.25	<b>O2-3</b>	Modeling the evolution of the surface profile of
		materials at low-energy ion sputtering
		A.S.Shumilov
		Yaroslavl branch of the Institute 3a Physics and
		Technology of Russian Academy of Science, Yaroslavl,
		Russia

#### 11.30-11.40 Coffee break

Se	ssion 4. <u>S</u>	pintronics and Magnetic Nanostructures
Session Chairn	man: V.V. I	Kostyuchenko
11.40-12.05	<b>I2-4</b>	Electric-field control of magnetic domain wall
	(invited)	motion and local magnetization reversal in
		multiferroic heterostructures
		Sebastiaan van Dijken
		Aalto University, Espoo, Finland
12.10-12.25	<b>O2-4</b>	New magnetic and magnetoelectric
		phenomena in tetrahedron single molecule
		magnets
		V.V.Kostyuchenko
		Yaroslavl Branch of the Institute of Physics and Technology,
		Russian Academy of Sciences, Yaroslavl, Russia
12.30-12.45	<b>O2-5</b>	Mössbauer study of magnetite nanoparticles surface
		M. Shipilin
		Yaroslavl State University named after P.G. Demidov,
		Yaroslavl, Russia
12.50-13.05	<b>O2-6</b>	Fabrication of InGaAs/GaAs light-emitting diodes
		with GaMnSb and GaMnAs ferromagnetic injector
		layer
		M.V. Dorokhin
		Physico-Technical Research Institute of Nizhny
		Novgorod State University, Nizhny Novgorod, Russia
		13.10-14.00 Lunch
<u>S</u>	Session 5.	Electronic transport in nanostructures
Session Chair	man: A.A. I	Popov
14.00-14.15	<b>O2-7</b>	The conductivity of DNA molecules

14.00-14.15	<b>O2-7</b>	The conductivity of DNA molecules
		T.I. Sharipov
		Bashkir State University, Ufa, Russia
14.20-14.35	<b>O2-8</b>	Electron transport in relaxed high doping transistor
		Si/Si <sub>1-x-v</sub> Ge <sub>x</sub> C <sub>v</sub> heterostructures
		M.L. Orlov
		Institute for Physics of Microstructures, Russian
		Academy of Sciences, N.Novgorod

14.40–14.55	O2-9	Antihysteresis in voltage-capacitance characteristic of MIS with multilayer insulator  A.A.Popov  Yaroslavl Branch of the Institute of Physics and Technology of Russian Academy of Sciences;  Yaroslavl, Russia
15.00-15.15	O2-10	Tunneling and current instability in two-miniband superlattices with unsymmetrical unit cell J.Yu. Romanova Institute for Physics of Microstructures, Russian Academy of Sciences, Nizhny Novgorod, Russia

#### 15.20-15.30 Coffee break

### Session 6. Perspective devices of micro and nanoelectronics

Session Chairi	man: II Ar	mirov
15.30-15.55	12-5	Gas Sensors Based on MEMS Platforms
10.00 10.00	(invited)	
	(III v I ccu)	Institute of Applied Chemical Physics, NRC "Kurchatov
		Institute", Moscow, Russia
16.00-16.15	<b>O2-11</b>	Principal Physical and Technological Problems and
10.00 10.10	02 11	Technical Solutions for Creating a New Generation
		of High-Temperature Microelectromechanical
		SOIMT Strain Sensors
		L.Sokolov
		Branch of MAI, "Strela", Zhukovsky, Russia
16.20-16.35	O2-12	Application of Amplitude Response of Scanning
10.20 10.33	02 12	Differential Heterodyne Microscope for
		Characterization of Triangular and Trapezoidal
		Plasmon Waveguides
		I. M. Akhmedzhanov
		A. M. Prokhorov General Physics Institute, Russian
		Academy of Sciences, Moscow
16.40-16.55	<b>O2-13</b>	KELVIN PROBE METHOD IN SCANNING
10.10 10.00	02 10	PROBE MICROSCOPY
		Salimov R. R
		Bashkir State university, Ufa, Russia
	1	7.00-19.00 POSTER SESSION I
	-	TIOU INTO I OUT OUT OF OUT OF OUT OF OUT OF OUT OF OUT OF OUT

19.00-22.00 Conference dinner

### Friday, May 25th, 2012

### Conference Hall in Park-Hotel Yaroslavl

### Session 7. Self-organization on the surface

Session Chairn	nan: V.I. I	Rudakov
9.00-9.15	<b>O3-1</b>	Forming of self-organizing nanostructures at laser
		heating
		A.O. Kecherik
		Department of Physics and Applied Mathematics,
		Stoletov's Vladimir State University, Vladimir, Russia
9.20-9.35	<b>O3-2</b>	Self-organization in adlayers on metallic
		nanosystems
		N. Socolova
		Frumkin Institute of Physical Chemistry and
		Electrochemistry, Russian Academy of Sciencies,
		Moscow, Russia
9.40-9.55	<b>O3-3</b>	Research of gas-sensitive cobalt-containing
		polyacrylonitrile films using the theory of self-
		organization
		S. Konovalenko
		Taganrog Pedagogical Institute named after A.P.
		Chekhov, Taganrog, Russia
		10.00-10.10 Coffee break

#### Session 8. Nanocomposites and porous media

10.10-10.25	<b>O3-4</b>	Formation of ordered structure of porous silicon in outside the electrodes discharge plasma
		M. Novozhenin
		Samara State Aerospace University, Samara, Russia
10.30-10.45	<b>O3-5</b>	Formation of fractal porous clusters in silicon
		A. V. Prokaznikov
		Yaroslavl Branch of the Institute of Physics and
		Technology, Russian Academy of Sciences, Yaroslavl,
		Russia
10.50-11.05	<b>O3-6</b>	Variation of the pore morphology for the porous
		lead selenide layers on silicon substrates
		S.P. Zimin
		Yaroslavl State University named after P.G.
		Demidov, Yaroslavl, Russia

11.10-11.25	O3-7	Calcium hydroxyapatite (HAp) and methylcellulose (MCel) interaction by their coprecipitation from aqueous solutions in the course of HAp/MCel nanosized biocomposites synthesis  N. Zakharov  Kurnakov Institute of General and Inorganic Chemistry of the Russian Academy of Science, Moscow, Russia
11.30-11.45	<b>O3-8</b>	New Generation of Lithium-ion Batteries:
		Role of Nanostructured Materials
		T. Kulova
		Frumkin Institute of Physical Chemistry and
		Electrochemistry, Russian Academy of Sciences,
		Moscow, Russia
11.50-12.05	<b>O3-9</b>	Structure, composition distribution and
		properties of the (Ga,Mn)Sb/GaAs and
		MnSb/GaAs heterosystems
		Yu.A. Danilov
		Physico-Technical Research Institute of University
12.10-12.25	O3-10	of Nizhni Novgorod, Nizhni Novgorod, Russia Structure and properties of ZnSSe
12.10-12.23	03-10	nanostructures embedded into nanoporous Al <sub>2</sub> O <sub>3</sub>
		films
		R. Valeev
		Physical-Technical Institute of Ural Branch of
		Physical-Technical Institute of Ural Branch of Russian Academy of Sciences, Izhevsk, Russia
12.30-12.45	03-11	Russian Academy of Sciences, Izhevsk, Russia
12.30-12.45	03-11	·
12.30-12.45	03-11	Russian Academy of Sciences, Izhevsk, Russia Nano-porous silicon produced by helium plasma
12.30-12.45	O3-11	Russian Academy of Sciences, Izhevsk, Russia Nano-porous silicon produced by helium plasma immersion ion implantation as a material for
12.30-12.45	O3-11	Russian Academy of Sciences, Izhevsk, Russia Nano-porous silicon produced by helium plasma immersion ion implantation as a material for photovoltaic applications

#### Session 9. Properties of micro and nanostructures

13.00-14.00 Lunch

Session Chairman: A. Prokaznikov

14.00-14.15 O3-12 Study on water adsorption on oxygen passivated silicon nanoparticles

R. Fedyuk

Far Eastern Federal University, Vladivostok, Russia

## 14.20-14.35 O3-13 Mechanism of microtribometric interaction of semiconductor wafers in assessment of surface cleanliness

V. Kolpakov

Image Processing Systems Institute of the RAS, Samara, Russia

#### Session 10. Ion to surface interactions

Session Chairman: V. Bachurin

14.40-14.55 O3-14 Particle trapping in various materials under low energy plasma irradiation

A. Ayrapetov

National Research Nuclear University MEPhI, Moscow, Russia

15.00-15.15 O3-15 The investigation of hydrogen sorptiondesorption process by carbon material with content of carbon nanotubes

L.Gulidova

Institute of Physics and Technology, Tomsk Polytechnic University, Tomsk, Russia

15.20-15.35 O3-16 Changes of surface layers composition, surface morphology and mechanical properties of carbon steel due to various parameters of ion irradiation P.V. Bykov

Physical-Technical Institute of the Ural Branch of the Russian Academy of Sciences, Izhevsk, Russia

15.40-15.55 O3-17 Nanomaker-the means of electron lithography for ultimate resolution

S. I. Zaitsev

Interface Ltd, Moscow, Russia

16.00-19.00 *POSTER SESSION II* 19.00 Conference closing

Saturday, May 26<sup>th</sup>, 2012
Departure of participants

#### **POSTER SESSIONS**

#### Thursday, May 24<sup>th</sup>, 2012

#### Conference Hall in Park-Hotel Yaroslavl

#### 16.00-19.00 *POSTER SESSION I*

P2-1 Electric current mechanics in reverse-biased p-i-n-structures under strong electrical field

V.S. Kuznetsov

Yaroslavl State University, Yaroslavl

P2-2 Geometric constraints of orbital entanglement production in normal conductors

S. Rodríguez-Pérez

Universidade Federal de São Carlos, São Carlos, SP, Brazil

P2-3 Molecular dynamics simulations of energy and impact angle of incidence of ions on the ion-plasma sputtering of copper

A.N. Kupriyanov

Yaroslavl branch of the Institute 3a Physics and Technology of Russian Academy of Science, Yaroslavl, Russia

P2-4 Surface alloying during Pd/Cu(100) deposition

O.S. Trushin

Yaroslavl branch of the Institute 3a Physics and Technology of Russian Academy of Science, Yaroslavl, Russia

P2-5 Modeling LINEAR defects in graphene and NANOGRAPHENE

V. Stelmakh

Arifov Institute of Electronics, Tashkent, Uzbekistan

P2-6 Micromagnetic modeling of spin-valve structure with technological imperfections

N. Barabanova

Yaroslavl State University, Yaroslavl, Russia

P2-7 Variational calculation of the image potential near a surface, taking into account the three-dimensional distribution of screening charge

S.E. Efimovsky

Northern State Medical University, Arkhangelsk, Russia

# P2-8 Application of ion implantation for making MIS nanotransistors with local area of the buried insulator S.A. Krivelevich

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences, Russia

P2-9 Conductance quantization of nanojunctions dynamically formed between two rough molybdenum surfaces observed in air at room temperature

L. Fedichkin

Institute of Physics and Technology, Russian Academy of Sciences, Moscow, Russia

P2-10 The effect of surface properties on electric absorption of fine metallic particles

I.A.Kuznetsova

Demidov Yaroslavl State University, Yaroslavl, Russia

P2-11 Dynamic effects of mossbauer spectroscopy for iron compounds in natural nanostructures

A. A. Zalutskii

Yaroslavl State Technical University, Yaroslavl, Russia

P2-12 Dependence of magnetic parameters on a thickness and formation conditions of permalloy films

A.V.Morozov

Yaroslavl State University, Yaroslavl, Russia

P2-13 Comparative study of ultrathin Co films grown by ionplasma and magnetron sputtering

V.F. Bochkarev

Yaroslavl Branch of the Institute of Physics and Technology of RAS, Yaroslavl, Russia

P2-14 Mössbauer study of ZnO implanted with iron ions at high temperature

E.N. Dulov

Kazan (Volga Region) Federal University, Kazan, Russia

## P2-15 The Influence of Superparamagnetism in Magnetic properties of the Alloy MnAl

V. Boydenko

P.G. Demidov Yaroslavl State University, Yaroslavl, Russia

## P2-16 Influence of an external magnetic field on the structure of granular Co-Cu films deposited by ion-plasmic method

#### Ed. Buchin

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences, Yaroslavl, Russia

### P2-17 Investigation of thermal characteristics and stability of Ge-Sb-Te-Ti thin films

A. Sherchenkov

National Research University of Electronic Technology, Moscow, Russia

### P2-18 Electrical and thermal properties of indium doped Ge<sub>2</sub>Sb<sub>2</sub>Te<sub>5</sub> thin films

P. Lazarenko

National Research University of Electronic Technology, Moscow, Russia

## P2-19 Stress fields within the cantilever console according to raman scattering

A. Kuzmenko

South-West State University, Kursk, Russia

### **P2-20** CW laser-induced nanomodification of PbX films S.V. Kutrovskaya

Stoletov's Vladimir State University, Vladimir, Russia

## P2-21 Vapor phase epitaxy fabrication of self-organized Mndoped InAs/GaAs quantum dot arrays

A.V. Zdoroveishev

Physico-Technical Research Institute of Nizhny Novgorod State University, Nizhny Novgorod, Russia

# P2-22 Multilayered photovoltaic structures based on tetrathiadiazoloporphyrazine/subphthalocyanine heterojunction

G. Pakhomov

Institute for Physics of Microstructures, Russian Academy of Sciences (IPM RAS), Nizhny Novgorod, Russia

# P2-23 Kelvin Probe Microscopy Studies of the Surface Potential Variations on the Si(111)/Me Surface S.V. Kazarinov

Department of Physical Electronics and Nanophysics Bashkir State University, Ufa, Russia

### P2-24 The carrier transport in the ferromagnetic quantum confined structures

A. Kudrin

Physico-Technical Research Institute of University of Nizhny Novgorod, Nizhny Novgorod, Russia

### **P2-25** Size effect in multilayer metallic nanocantilevers I.V. Uvarov

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences, Yaroslavl, Russia

## P2-26 Influence of the conditions of ion-plasma sputtering on the surface roughness of platinum film

R.V. Selyukov

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences, Yaroslavl, Russia

#### Friday, May 25th, 2012

#### Conference Hall in Park-Hotel Yaroslavl

#### 16.00-19.00 *POSTER SESSION II*

P3-1 Laser synthesis of nanostructures

A. Antipov

Stoletov Vladimir State University, Vladimir, Russia

P3-2 Synthesis of transparent carbon films with operated morphology in constant electric field

A. Osipov

Stoletov Vladimir State University, Vladimir, Russia

P3-3 Oscillations profiles of thermoelectric parameters in nanostructures on the base of lead telluride
D. Freik

Physics and chemistry institute at PreCarpathian Vasyl Stefanyk National University, Ivano-Frankivsk, Ukraine

P3-4 Technology features silicon nanostructured electrodes for lithium-ion batteries

A.E. Berdnikov.

Yaroslavl Branch of Physics and Technology Institute of Russian Academy of Sciences, Yaroslavl, Russia

### P3-5 Layer cold cathodes based on nanostructured diamond-like materials

A. Belyanin

Central Research Technological Institute "TECHNOMASH", Moscow, Russia

## P3-6 Effect of annealing on formation of *high-k* insulators in the W/ultrathin HfO<sub>2</sub>/Si (100) system

V. Rudakov

Yaroslavl Branch of the Institute of Physics and Technology RAS,, Yaroslavl, Russia

## P3-7 Investigation of Cement Structure Formation by Small-Angle Neutron Scattering Experiments

A. Guryanov

Samara State University of Architecture and Civil Engineering, Samara, Russia

## P3-8 Electrical properties of plasma-chemical silicon dioxide processed by boiling water in the metal - oxide - metal structure

V. Levin

Yaroslavl Branch of the Institute of Physics and Technology, Yaroslavl, Russia

### P3-9 Photosensitive and luminescence porous silicon based structures

N. Latukhina

Samara State University, Samara, Russia

# P3-10 The features of interactions of disilane molecular beam with the epitaxial surface in conditions of silicon layer growth

N.L.Ivina

Nizhni Novgorod Management Institute, Nizhni Novgorod, Russia

### P3-11 Low-frequency noise spectroscopy as a diagnostic tool to study of surfaces

M. Makoviychuk

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences, Yaroslavl, Russia

# P3-12 Neural network modeling for prediction of gassensitivity of Ag-containing polyacrylonitrile films T.A.Bednaya

Taganrog State Pedagogical Institute, Taganrog, Russia

P3-13 Three-dimensional model of adsorption-diffusion-reaction processes with a Tri-State
N. A. Rud

Yaroslavl Demidov State University, Yaroslavl, Russia

# P3-14 Incorporation in grow film previously produced nanosize particles during low frequency PECVD A.E.Berdnikov

Yaroslavl Branch of the Institute of Physics and Technology, Russian Academy of Sciences; Yaroslavl, Russia

## P3-15 Aluminum Nanoisland Films Formation under the Electron Irradiation of the Sapphire Surface

I.P. Ivanenko

Physics Department, Moscow State University, Moscow, Russia

## P3-16 Particle trapping in stainless steel in oxygen contaminated deuterium plasma

L. Begrambekov

National Research Nuclear University (MEPhI), Moscow, Russia

# P3-17 Hydrogen trapping in zirconium and zirconium with chromium coating under hydrogen saturation in various conditions

L. Begrambekov

National Research Nuclear University "MEPhI", Moscow, Russia

## P3-18 Ion implantation of rolled copper-nickel foils and manifestations of long-range effect

A. A. Novoselov

Physical-Technical Institute UrB RAS, Izhevsk, Russia

P3-19 THE FEATURES OF INTERACTION OF DISILANE MOLECULAR BEAM WITH THE EPITAXIAL SURFACE IN CONDITIONS OF SILICON LAYER GROWTH

L.K. Orlov

NNSThU, Nizhni Novgorod, Russia

P3-20 Investigation of the surface structure of solids and liquids by ellipsometry in a severe mathematical incorrectness of the inverse problem.

A.I. Semenenko

State University, Sumy, Ukraine

## P3-21 Simulation of bone tissue/carbon nanotubes interaction during biomineralization

N. Zakharov

Kurnakov Institute of General and Inorganic Chemistry of the Russian Academy of Science, Moscow, Russia

## P3-22 Effect of multi – walled carbon nanotube on tribological properties of field and lubricant N. Savinski

Yaroslavl branch of of Physics & Technology Institute of Russian Academy of Sciences, Yaroslavl, Russia

### **P3-23** The study of the dynamics of calcifying nanoparticles O.Y. Prikhodko

Facilities Sharing Centre "Micro- and Nanostructures Diagnosis", Demidov State University, Yaroslavl, Russia

### P3-24 Fraktalnaja processing of surfaces of cancer diseases of a skin

L. Nefed'ev

Physics institute, the Kazan (Privolzhsky) federal university, Kazan, Russia

## P3-25 Self-organization of oligopeptides thin films due to organic vapors

I.G. Efimova

Kazan (Volga region) federal university, Kazan, Russia

### P3-26 Application of ion beam cutting for multi-layered metal/oxide system

N. Suhodoeva

Polytechnic institute of Siberian Federal University, Krasnoyarsk, Russia